



SANYO Semiconductors

DATA SHEET

SFT1405

N-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Motor drive application.
- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		45	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		10	A
Drain Current (PW≤10μs)	I _{DP}	PW≤10μs, duty cycle≤1%	40	A
Allowable Power Dissipation	P _D		1.0	W
		Tc=25°C	15	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0V	45			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =45V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =5A	3.6	6		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =5A, V _{GS} =10V		34	45	mΩ
	R _{DS(on)2}	I _D =5A, V _{GS} =4V		53	74	mΩ

Marking : T1405

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SFT1405

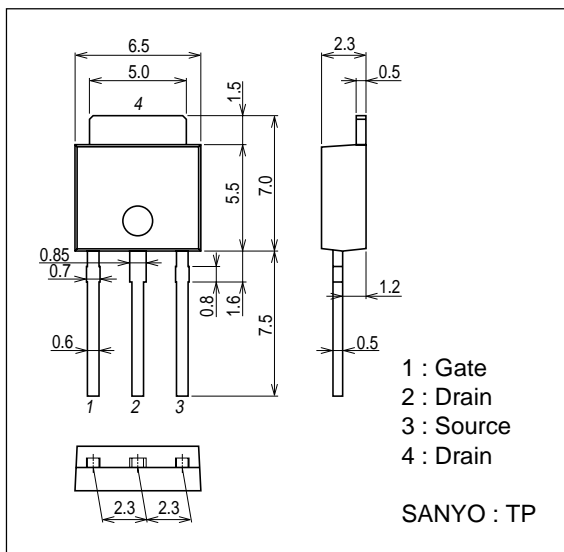
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		860		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		105		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		75		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		14		ns
Rise Time	t _r	See specified Test Circuit.		64		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		60		ns
Fall Time	t _f	See specified Test Circuit.		65		ns
Total Gate Charge	Q _g	V _{DS} =24V, V _{GS} =10V, I _D =10A		18.1		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =24V, V _{GS} =10V, I _D =10A		2.6		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =24V, V _{GS} =10V, I _D =10A		4		nC
Diode Forward Voltage	V _{SD}	I _S =10A, V _{GS} =0V		0.97	1.2	V

Package Dimensions

unit : mm (typ)

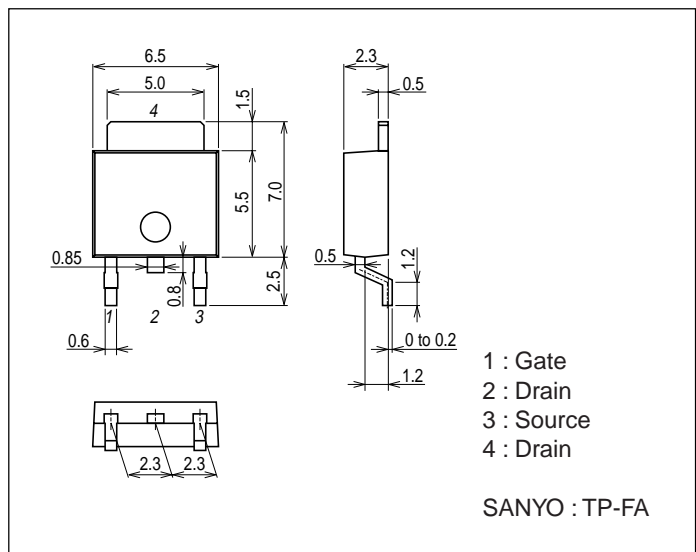
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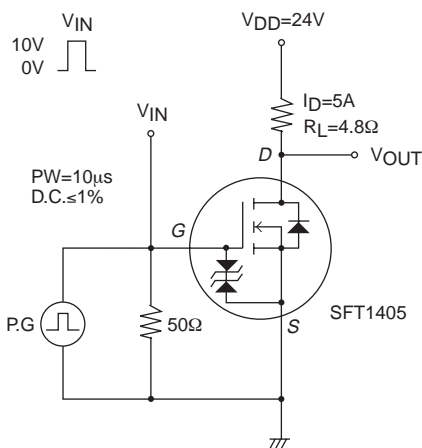
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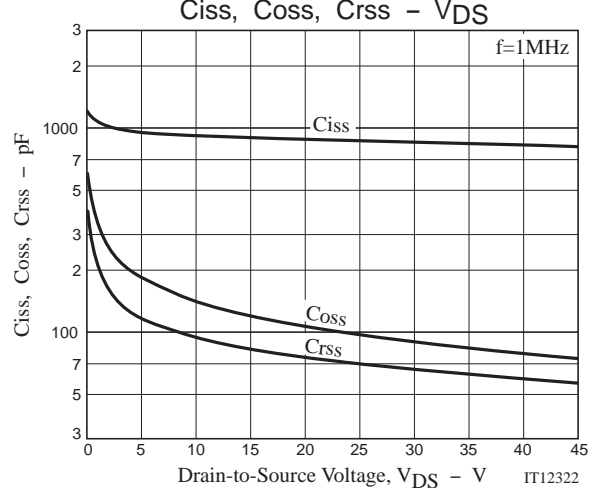
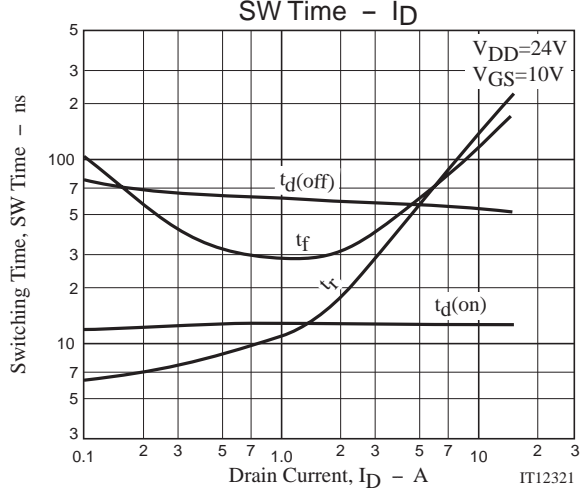
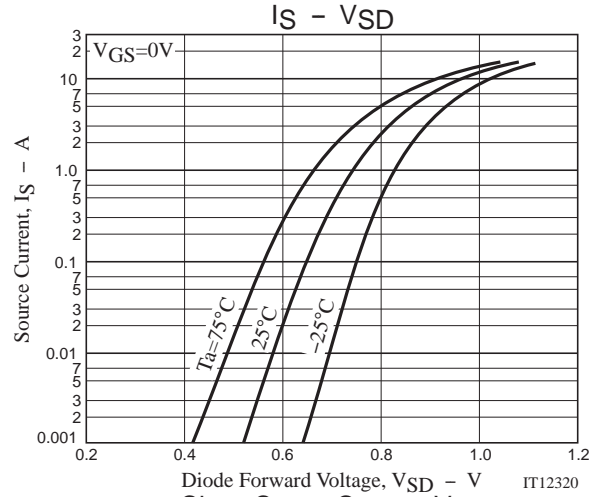
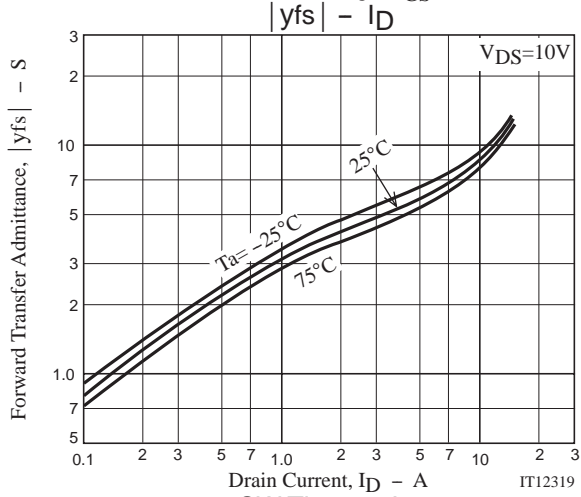
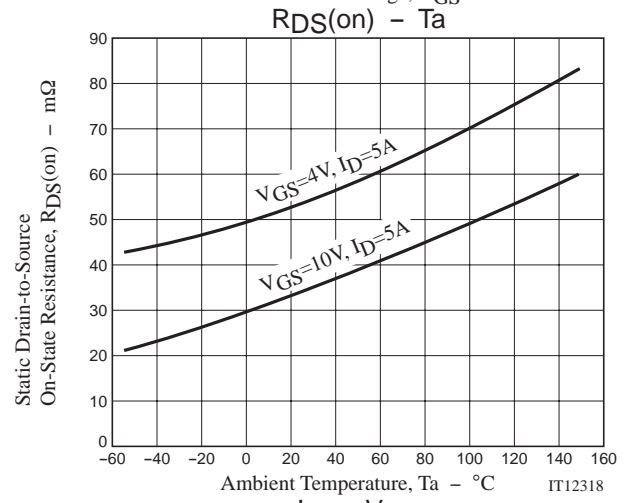
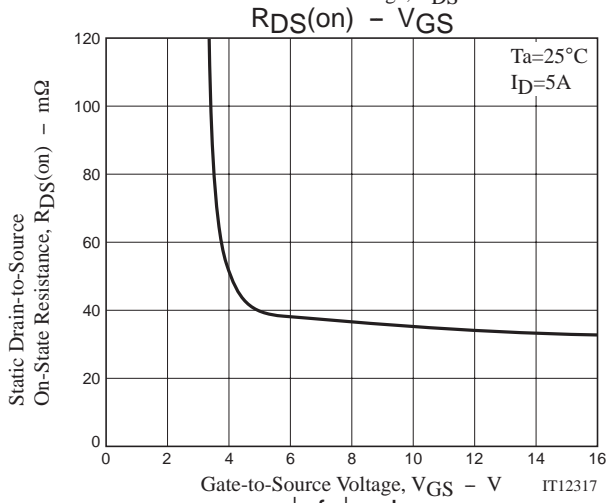
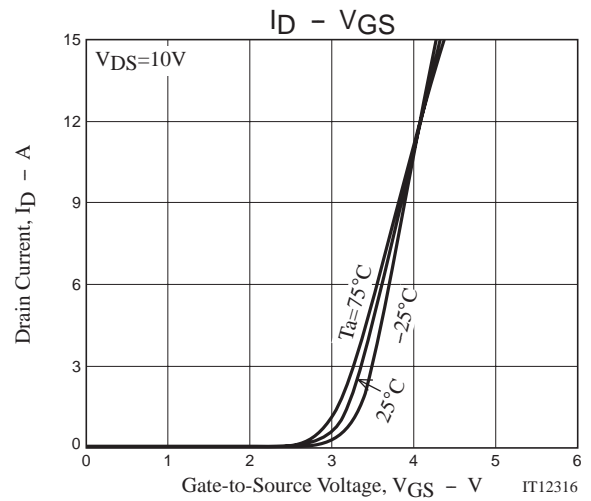
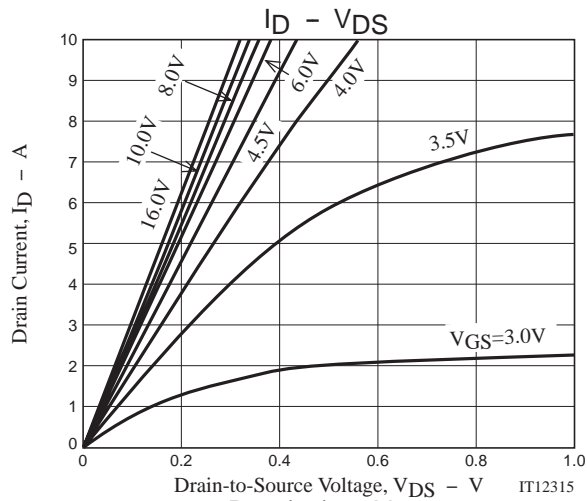
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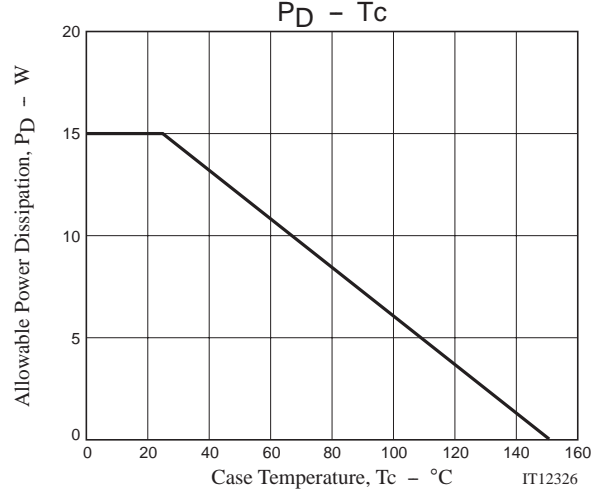
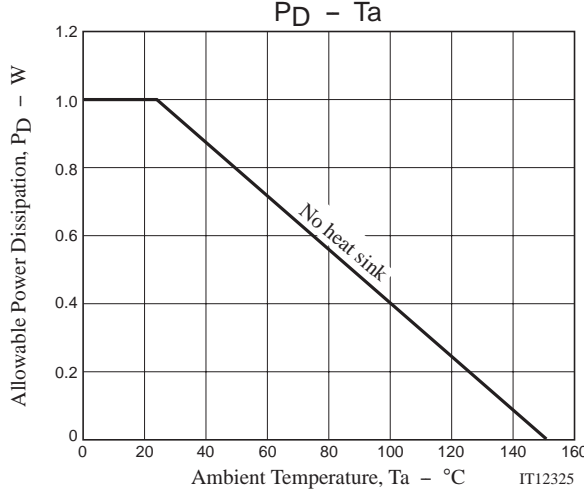
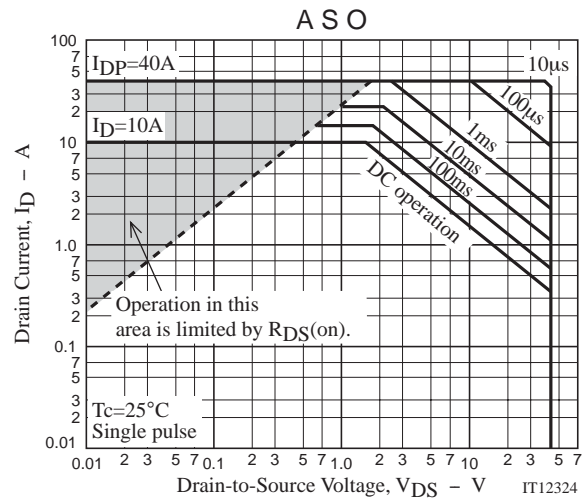
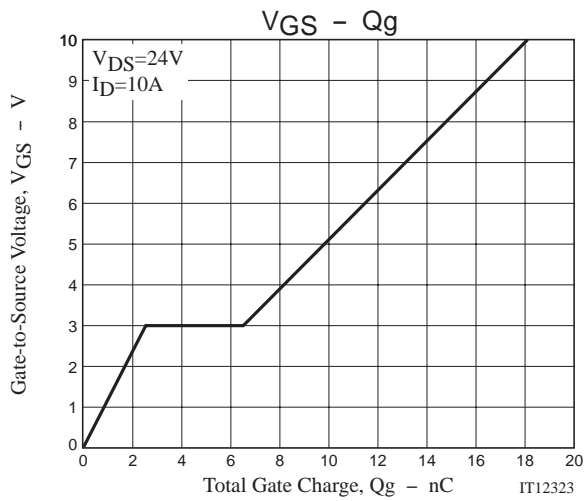
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Switching Time Test Circuit







Note on usage : Since the SFT1405 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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